

High and Low Side Driver

Features

- Gate drive supplies up to 20V per channel
- Undervoltage lockout for V_{CC} , V_{BS}
- 3.3 V, 5V, 15V input logic compatible
- Tolerant to negative transient voltage
- Designed for use with bootstrap power supplies
- Matched propagation delays
- Output in phase with the Inputs
- -40°C to 125°C operating range
- RoHS compliant

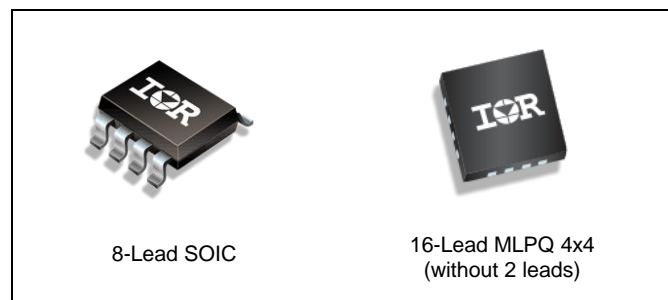
Description

The IRS2005 is a high voltage, high speed power MOSFET and IGBT driver with independent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 200 V. Propagation delays are matched to simplify the HVIC's use in high frequency applications.

Product Summary

| | |
|--|--------------------|
| V_{OFFSET} | $\leq 200\text{V}$ |
| V_{OUT} | 10 V – 20V |
| $I_{\text{o+}} \& I_{\text{o-}}$ (typ.) | 290mA & 600mA |
| $t_{\text{ON}} \& t_{\text{OFF}}$ (typ.) | 160ns & 150ns |
| Delay matching (max.) | 50ns |

Package Options

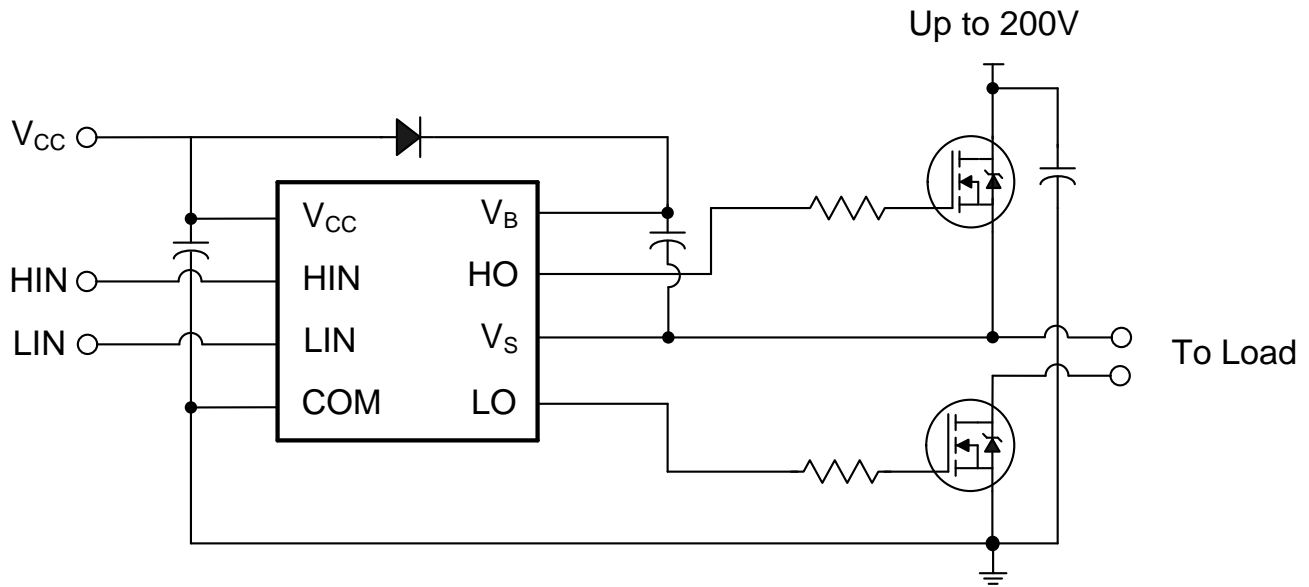


Typical Applications

- Appliance motor drives
- Servo drives
- Micro inverter drives
- General purpose three phase inverters

| Base Part Number | Package Type | Standard Pack | | Orderable Part Number |
|------------------|------------------|---------------|----------|-----------------------|
| | | Form | Quantity | |
| IRS2005SPBF | 8-Lead SOIC | Tube/Bulk | 95 | IRS2005SPBF |
| | | Tape and Reel | 2500 | IRS2005STRPBF |
| IRS2005MPBF | 14-Lead MLPQ 4x4 | Tape and Reel | 3000 | IRS2005MTRPBF |

Typical Connection Diagram



(Refer to Lead Assignments for correct pin configuration). This diagram shows electrical connections only. Please refer our Application Notes & DesignTips for proper circuit board layout.

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM unless otherwise stated in the table. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

| Symbol | Definition | Min. | Max. | Units | |
|---------------------|--|----------------------|-----------------------|-------|------|
| V _{CC} | Low side supply voltage | -0.3 | 25 [†] | V | |
| V _{IN} | Logic input voltage | COM - 0.3 | V _{CC} + 0.3 | | |
| V _B | High-side floating well supply voltage | -0.3 | 225 | | |
| V _S | High-side floating well supply return voltage | V _B - 25 | V _B + 0.3 | | |
| V _{HO} | Floating gate drive output voltage | V _S - 0.3 | V _B + 0.3 | | |
| V _{LO} | Low-side output voltage | COM - 0.3 | V _{CC} + 0.3 | | |
| COM | Power ground | V _{CC} - 25 | V _{CC} + 0.3 | | |
| dV _S /dt | Allowable V _S offset supply transient relative to COM | — | 50 | V/ns | |
| P _D | Package power dissipation @ T _A ≤ +25°C | 8-Lead SOIC | — | 0.625 | W |
| | | 14-Lead MLPQ 4x4 | — | 2.08 | |
| R _{thJA} | Thermal resistance, junction to ambient | 8-Lead SOIC | — | 200 | °C/W |
| | | 14-Lead MLPQ 4x4 | — | 36 | |
| T _J | Junction temperature | — | 150 | °C | |
| T _S | Storage temperature | -55 | 150 | | |
| T _L | Lead temperature (soldering, 10 seconds) | — | 300 | | |

† All supplies are tested at 25V.

Recommended Operating Conditions

For proper operation, the device should be used within the recommended conditions. All voltage parameters are absolute voltages referenced to COM unless otherwise stated in the table. The offset rating is tested with supplies of (V_{CC} - COM) = (V_B - V_S) = 15V.

| Symbol | Definition | Min | Max | Units |
|-----------------|--|----------------------|---------------------|-------|
| V _{CC} | Low-side supply voltage | 10 | 20 | V |
| V _{IN} | Logic input voltage | 0 | V _{CC} | |
| V _B | High-side floating well supply voltage | V _S + 10 | V _S + 20 | |
| V _S | High-side floating well supply offset voltage [†] | COM - 8 [†] | 200 | |
| V _{HO} | Floating gate drive output voltage | V _S | V _B | |
| V _{LO} | Low-side output voltage | COM | V _{CC} | |
| T _A | Ambient temperature | -40 | 125 | °C |

† Logic operation for V_S of -8 V to 200 V. Logic state held for V_S of -8 V to -V_{BS}. Please refer to Design Tip DT97-3 for more details.

Static Electrical Characteristics

$(V_{CC} - COM) = (V_B - V_S) = 15V$. $T_A = 25^\circ C$ unless otherwise specified. The V_{IN} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to respective V_S and COM and are applicable to the respective output leads HO or LO. The V_{CCUV} parameters are referenced to COM. The V_{BSUV} parameters are referenced to V_S .

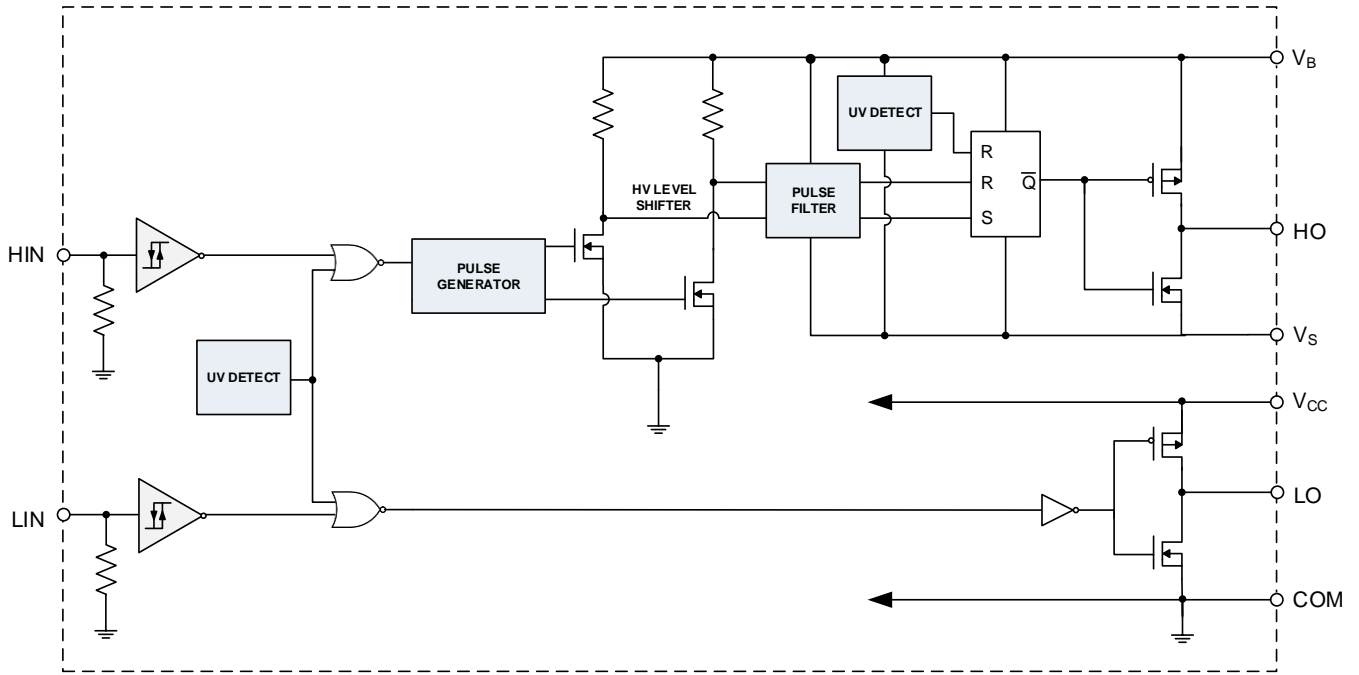
| Symbol | Definition | Min. | Typ. | Max. | Units | Test Conditions |
|--------------|---|------|------|------|---------|---|
| V_{BSUV+} | V_{BS} supply undervoltage positive going threshold | 8.0 | 8.9 | 9.8 | V | |
| V_{BSUV-} | V_{BS} supply undervoltage negative going threshold | 7.4 | 8.2 | 9 | | |
| V_{BSUVHY} | V_{BS} supply undervoltage hysteresis | — | 0.7 | — | | |
| V_{CCUV+} | V_{CC} supply undervoltage positive going threshold | 8.0 | 8.9 | 9.8 | | |
| V_{CCUV-} | V_{CC} supply undervoltage negative going threshold | 7.4 | 8.2 | 9 | | |
| V_{CCUVHY} | V_{CC} supply undervoltage hysteresis | — | 0.7 | — | | |
| I_{LK} | High-side floating well offset supply leakage | — | — | 50 | μA | $V_B = V_S = 200V$ |
| I_{QBS} | Quiescent V_{BS} supply current | — | 45 | 75 | | All inputs are in the off state |
| I_{QCC} | Quiescent V_{CC} supply current | — | 300 | 520 | | |
| V_{OH} | High level output voltage drop, $V_{BIAS} - V_O$ | — | 0.05 | 0.2 | V | $I_O = 2\text{ mA}$ |
| V_{OL} | Low level output voltage drop, V_O | — | 0.02 | 0.1 | | |
| I_{O+} | Output high short circuit pulsed current | 200 | 290 | — | mA | $V_O = 0V, V_{IN} = 0V$ $PW \leq 10\mu s$ |
| I_{O-} | Output low short circuit pulsed current | 420 | 600 | — | | $V_O = 15V, V_{IN} = 5V$ $PW \leq 10\mu s$ |
| V_{IH} | Logic "1" input voltage | 2.5 | — | — | V | |
| V_{IL} | Logic "0" input voltage | — | — | 0.8 | | |
| I_{IN+} | Input bias current (HO = High) | — | 3 | 10 | μA | $V_{IN} = 5V$ |
| I_{IN-} | Input bias current (HO = Low) | — | — | 5 | | $V_{IN} = 0V$ |

Dynamic Electrical Characteristics

$V_{CC} = V_B = 15V$, $V_S = COM$, $T_A = 25^\circ C$, and $C_L = 1000pF$ unless otherwise specified.

| Symbol | Definition | Min. | Typ. | Max. | Units | Test Conditions |
|-----------|--|------|------|------|-------|----------------------|
| t_{ON} | Turn-on propagation delay | — | 160 | 220 | ns | $V_S = 0V$ or $200V$ |
| t_{OFF} | Turn-off propagation delay | — | 150 | 220 | | |
| t_R | Turn-on rise time | — | 70 | 170 | | $V_S = 0V$ |
| t_F | Turn-off fall time | — | 30 | 90 | | |
| t_{FIL} | Minimum pulse input filter time | — | 300 | — | | |
| MT | Delay matching time (t_{ON} , t_{OFF}) | — | — | 50 | | |

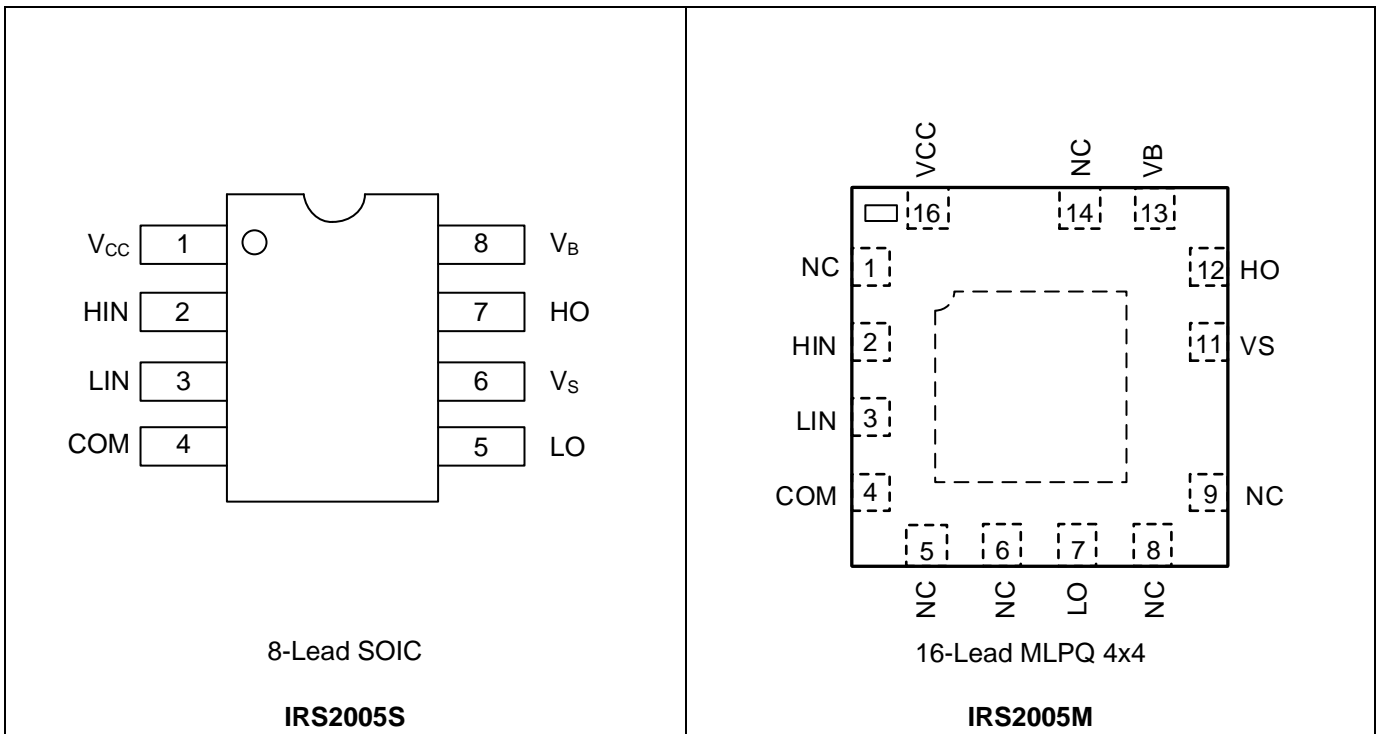
Functional Block Diagram



Lead Definitions

| Symbol | Description |
|--------|--|
| VCC | Low-side and logic supply voltage |
| VB | High-side gate drive floating supply |
| VS | High voltage floating supply return |
| HIN | Logic inputs for high-side gate driver output (HO), in phase |
| LIN | Logic inputs for low-side gate driver output (LO), in phase |
| HO | High-side driver output |
| LO | Low-side driver output |
| COM | Low-side gate drive return |

Lead Assignments



Application Information and Additional Details

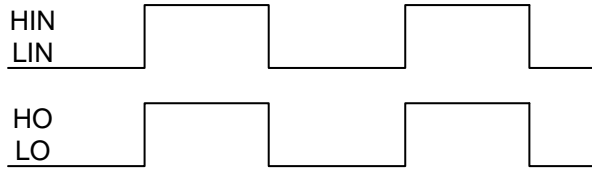


Figure 1. Input/Output Timing Diagram

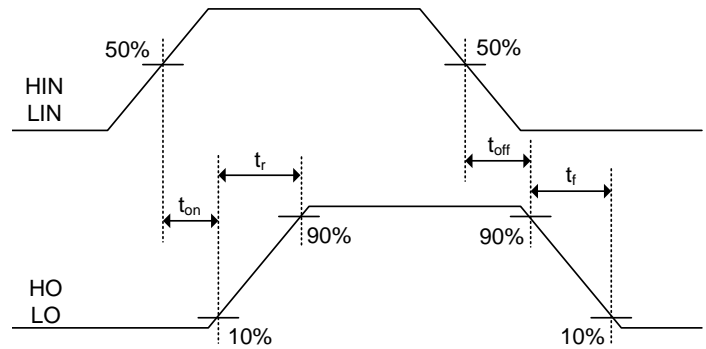


Figure 2. Switching Time Waveform Definitions

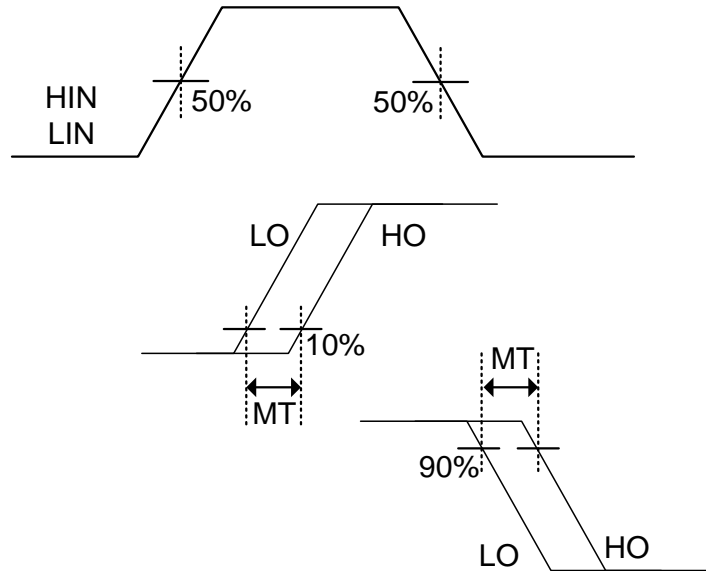


Figure 3. Delay Matching Waveform Definitions

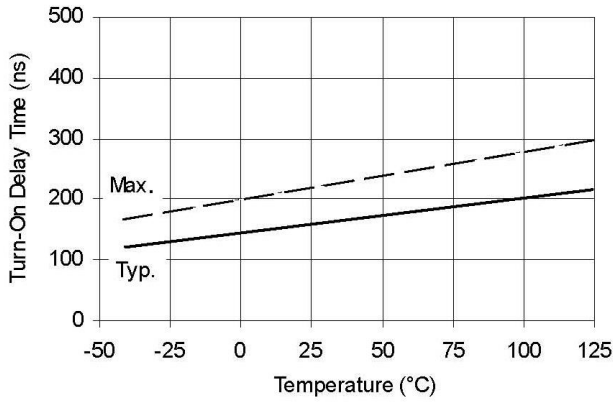


Figure 4A. Turn-On Delay Time vs. Temperature

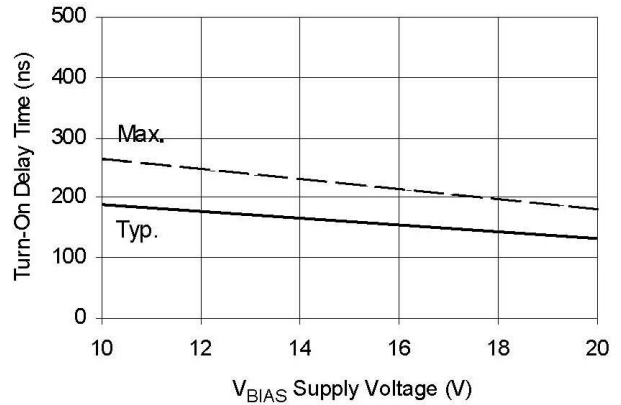


Figure 4B. Turn-On Delay Time vs. Supply Voltage

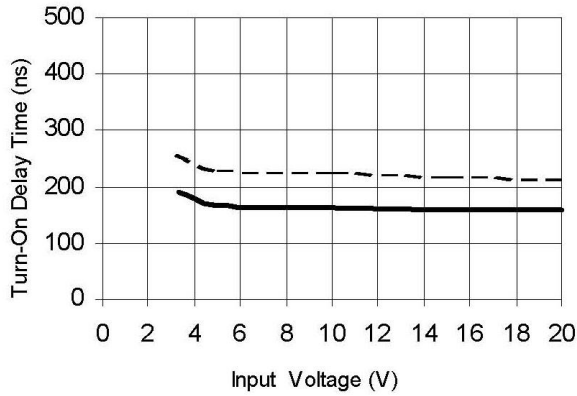


Figure 4C. Turn-On Delay Time vs. Input Voltage

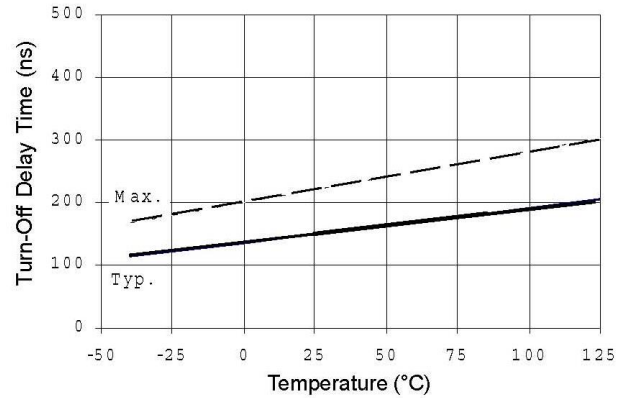


Figure 5A. Turn-Off Delay Time vs. Temperature

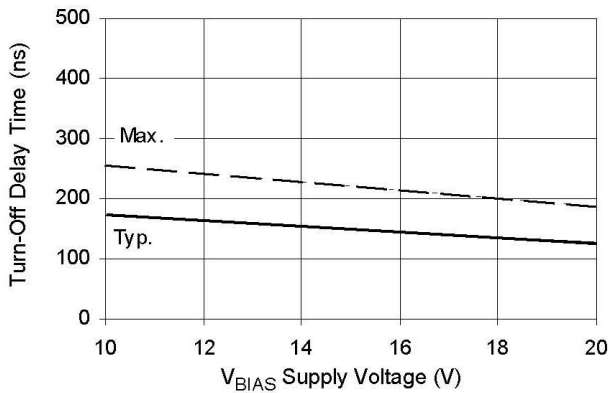


Figure 5B. Turn-Off Delay Time vs. Supply Voltage

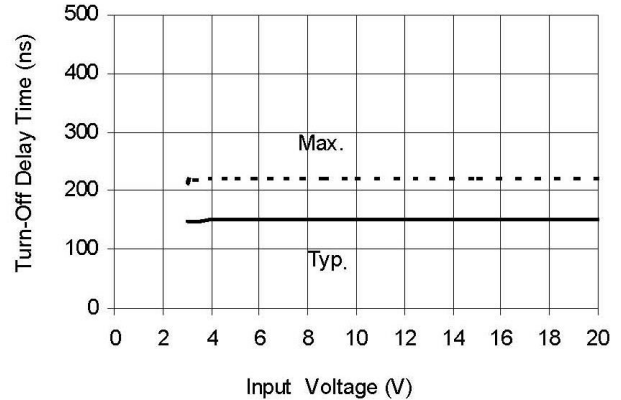


Figure 5C. Turn-Off Time vs. Input Voltage

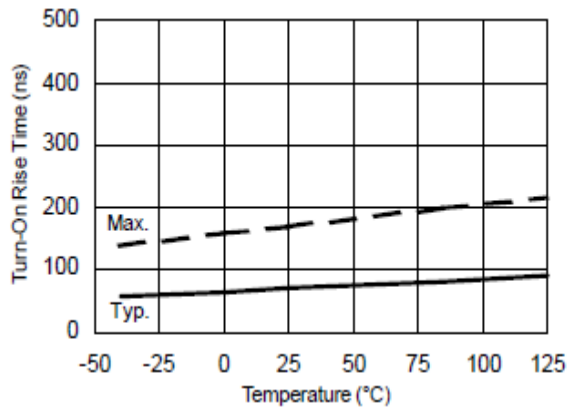


Figure 6A. Turn-On Rise Time vs. Temperature

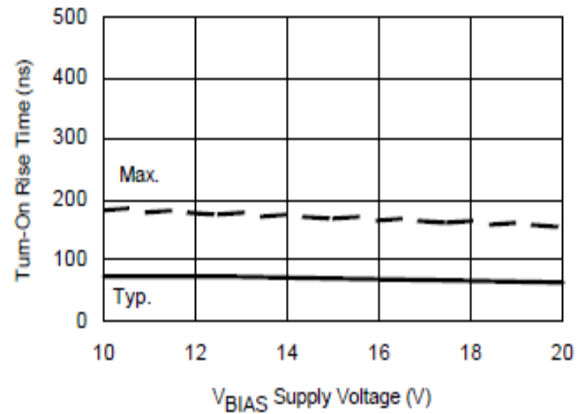


Figure 6B. Turn-On Rise Time vs. Voltage

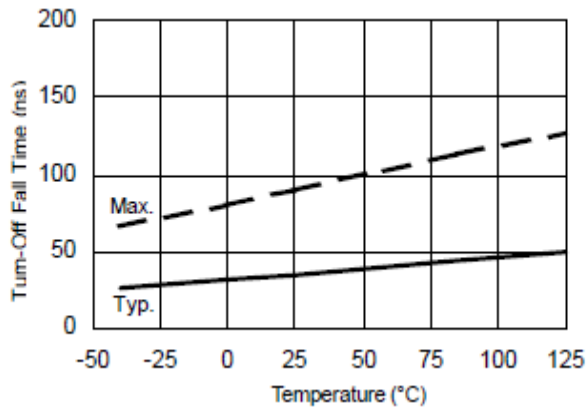


Figure 7A. Turn-Off Fall Time vs. Temperature

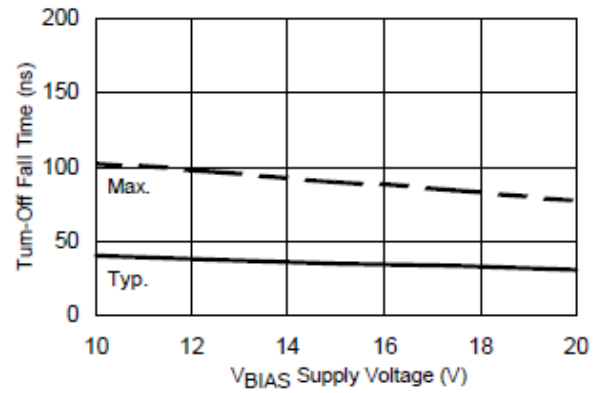


Figure 7B. Turn-Off Fall Time vs. Voltage

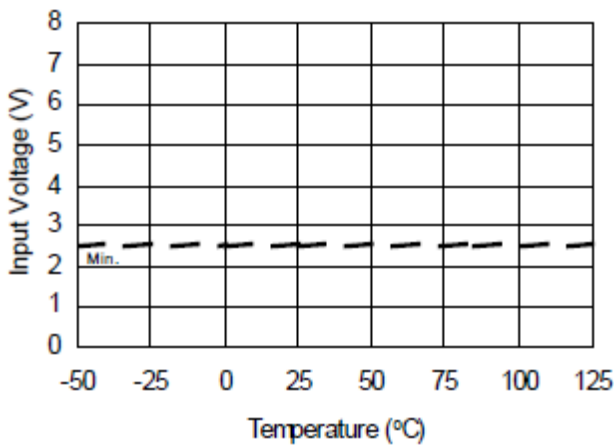


Figure 8A. Logic "1" Input Voltage vs. Temperature

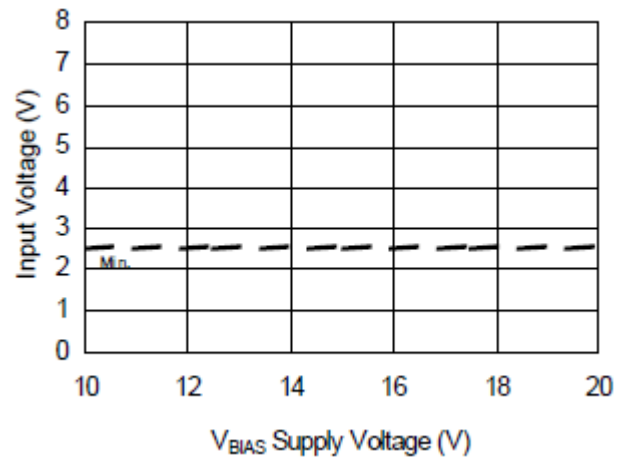


Figure 8B. Logic "1" Input Voltage vs. Voltage

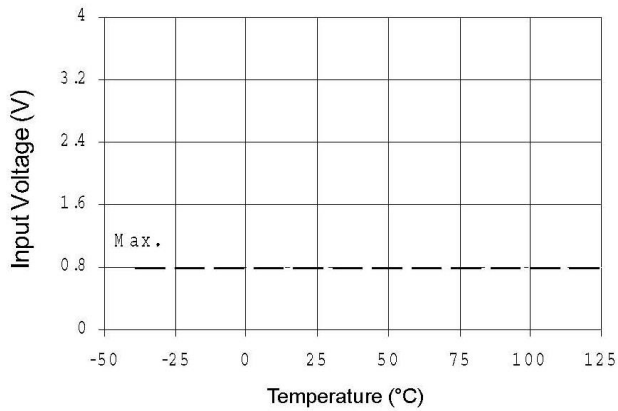


Figure 9A. Logic “0” Input Voltage vs. Temperature

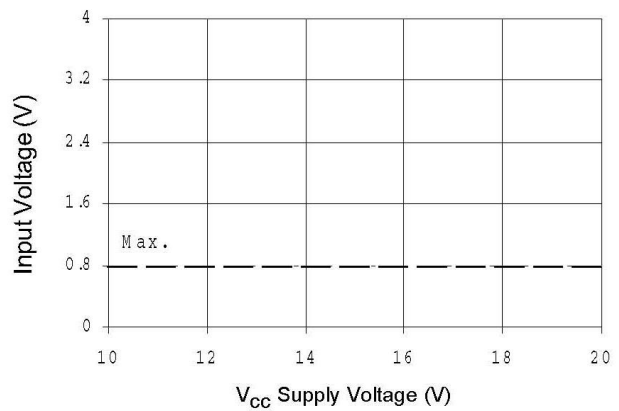


Figure 9B. Logic “0” Input Voltage vs. Supply Voltage

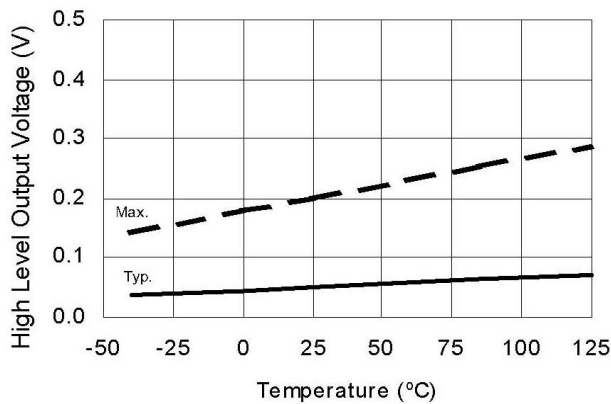


Figure 10A. High Level Output Voltage vs. Temperature

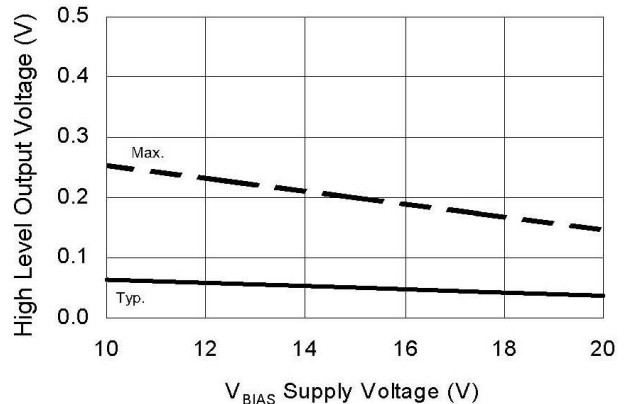


Figure 10B. High Level Output vs. Supply Voltage

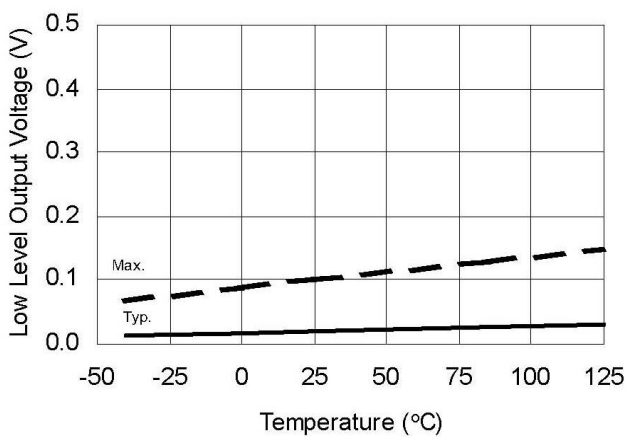


Figure 11A. Low Level Output Voltage vs. Temperature

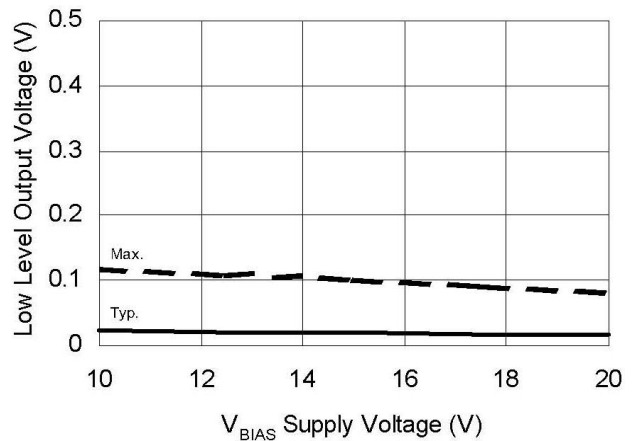


Figure 11B. Low Level Output vs. Supply Voltage

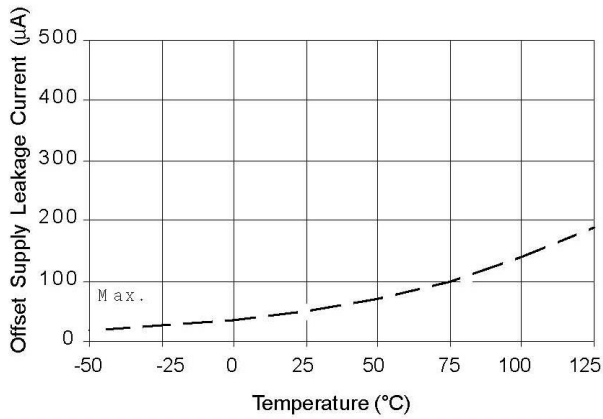


Figure 12A. Offset Supply Current vs. Temperature

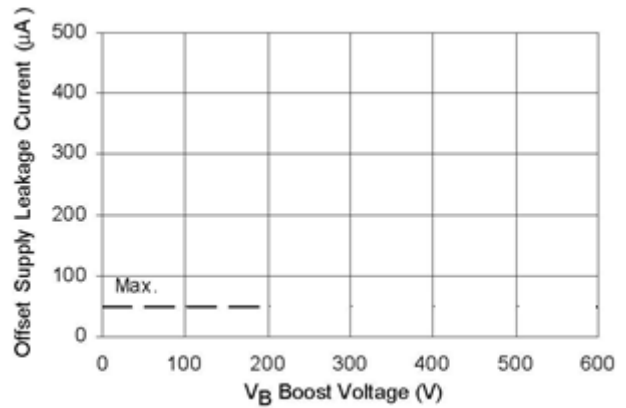


Figure 12B. Offset Supply Current vs. Voltage

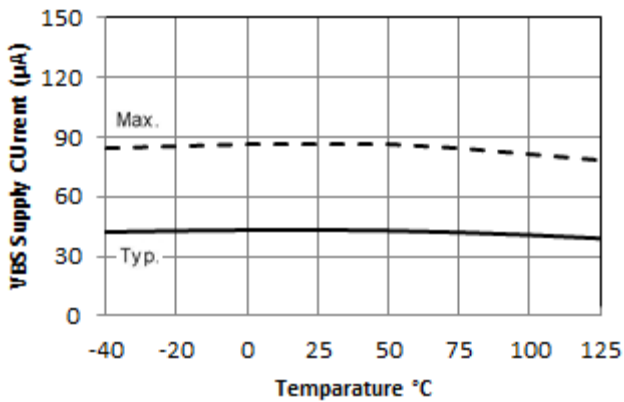


Figure 13A. V_{BS} Supply Current vs. Temperature

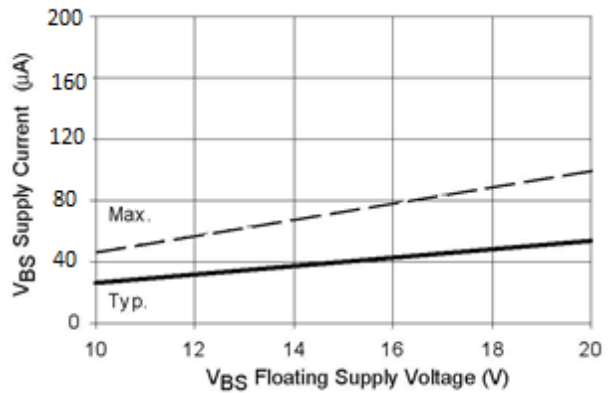


Figure 13B. V_{BS} Supply Current vs. Voltage

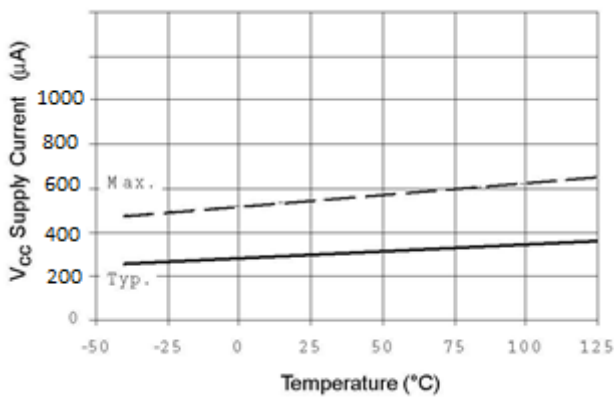


Figure 14A. V_{CC} Supply Current vs. Temperature

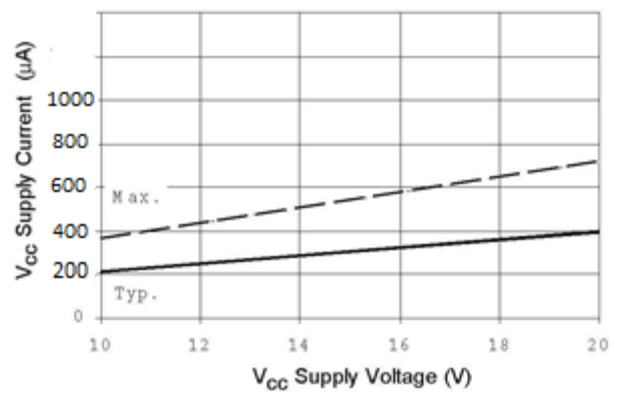


Figure 14B. V_{CC} Supply Current vs. Voltage

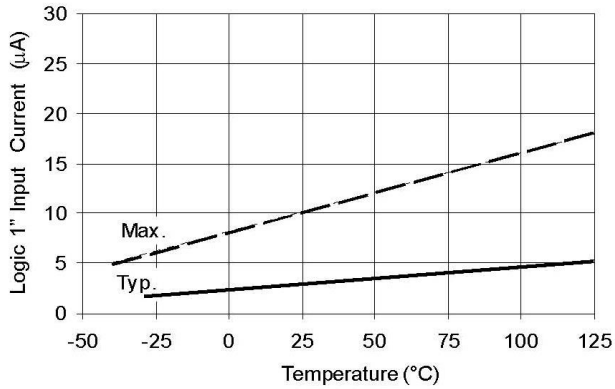


Figure 15A. Logic "1" Input Current vs. Temperature

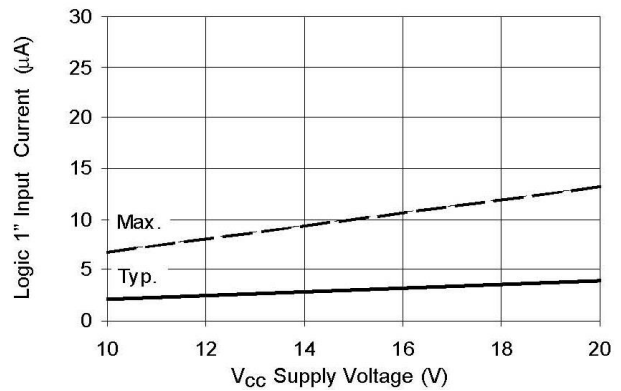


Figure 15B. Logic "1" Input Current vs. Voltage

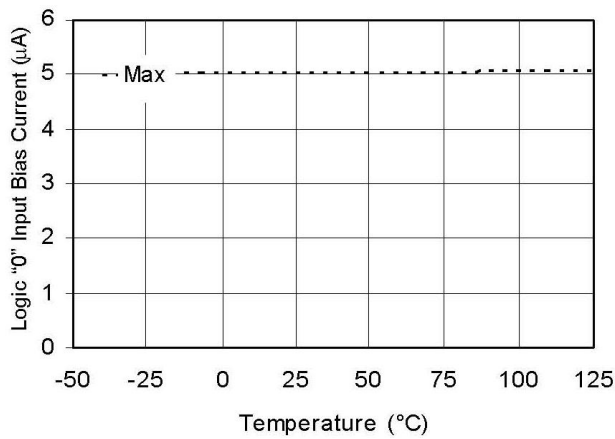


Figure 16A. Logic "0" Input Bias Current

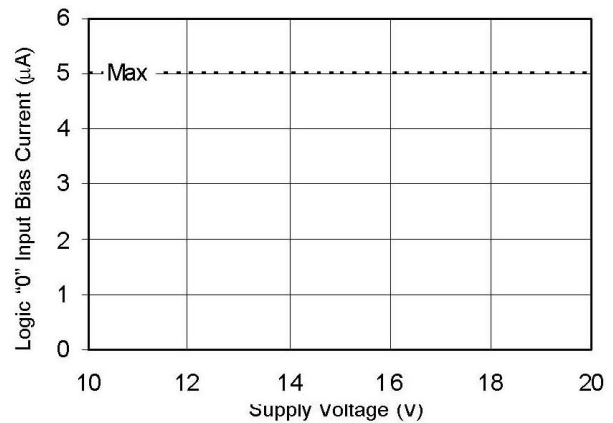


Figure 16B. Logic "0" Input Bias Current

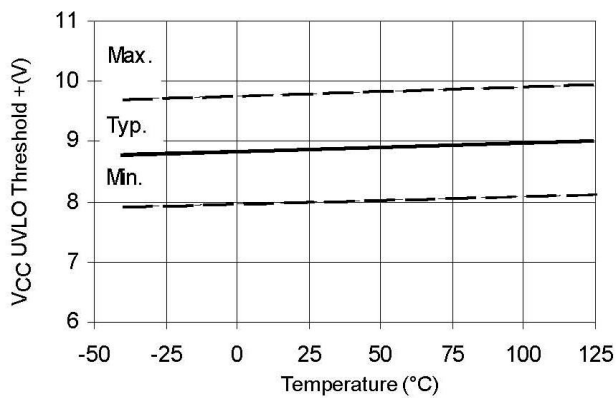


Figure 17A. V_{CC}/V_{BS} Undervoltage Threshold(+) vs. Temperature

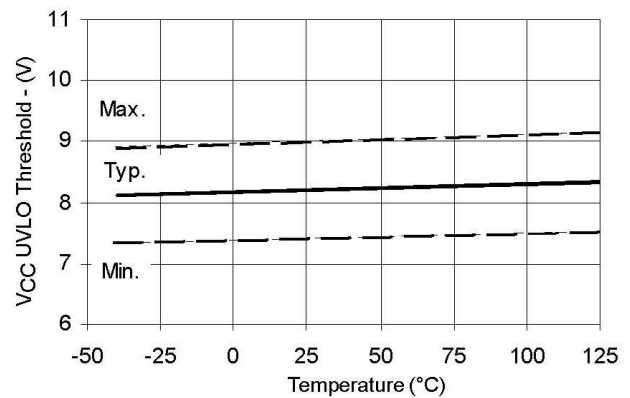


Figure 17B. V_{CC}/V_{BS} Undervoltage Threshold(-) vs. Temperature

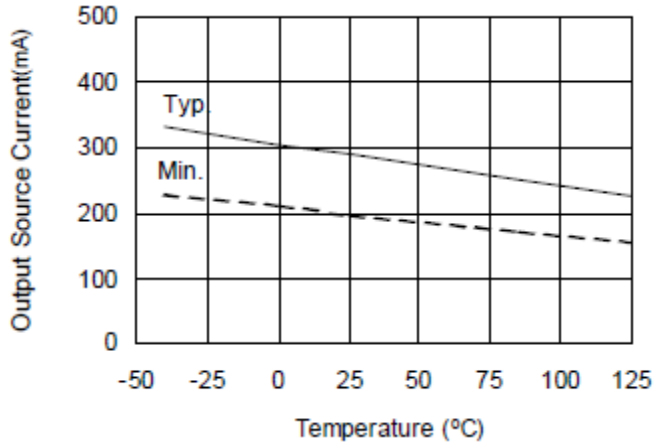


Figure 18A. Output Source Current vs. Temperature

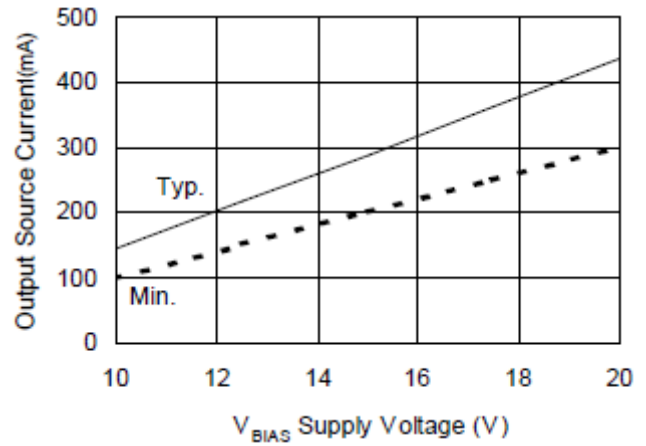


Figure 18B. Output Source Current vs. Supply Current

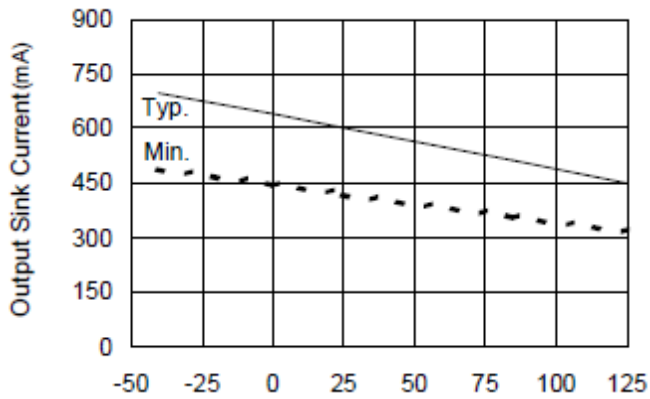


Figure 19A. Output Sink Current vs. Temperature

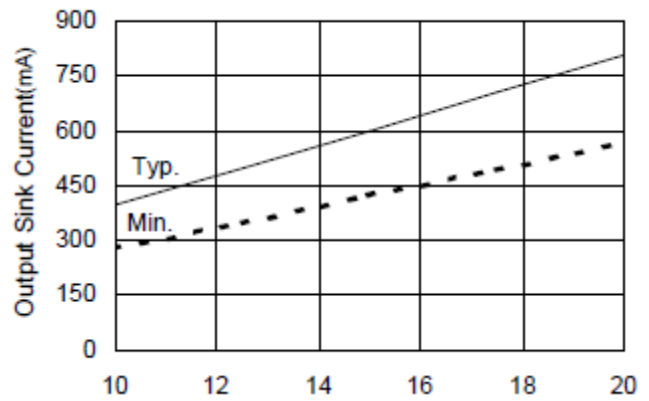
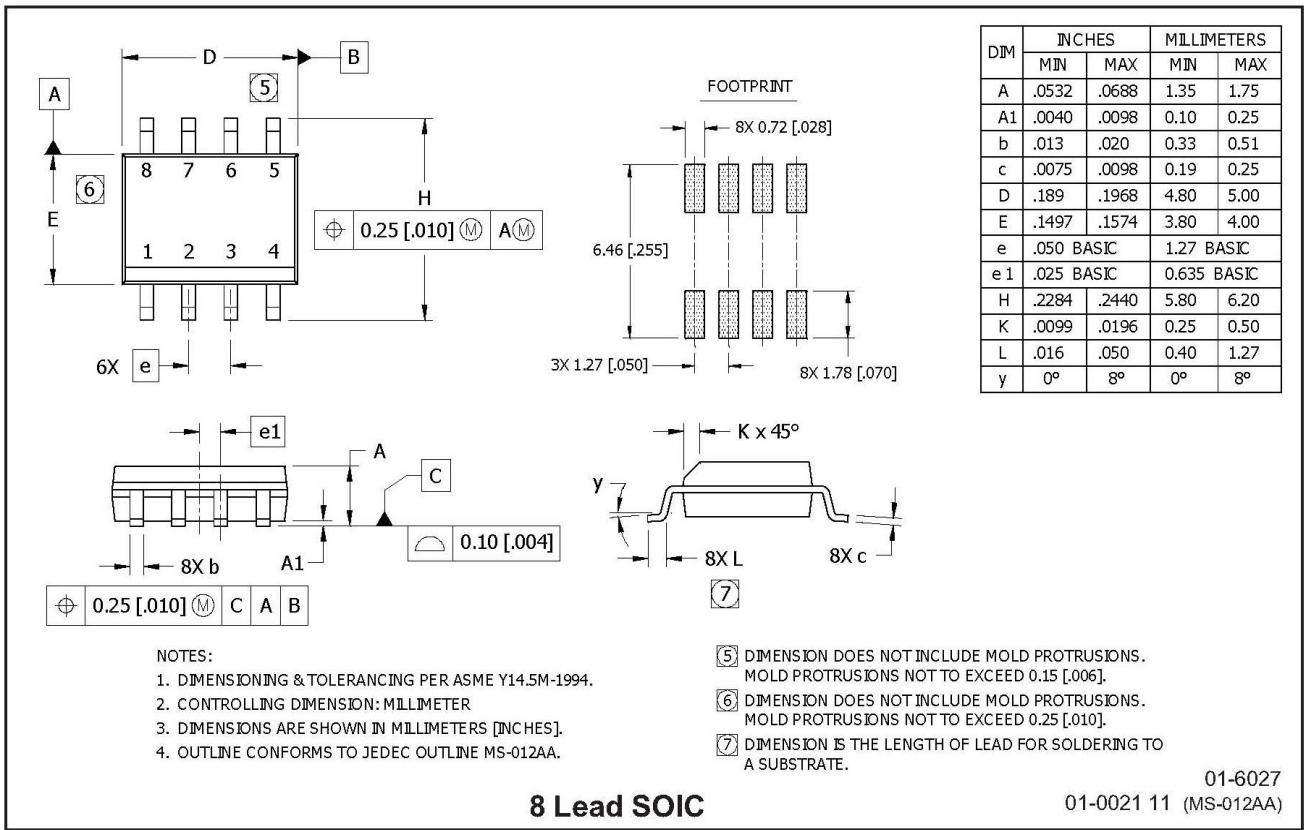
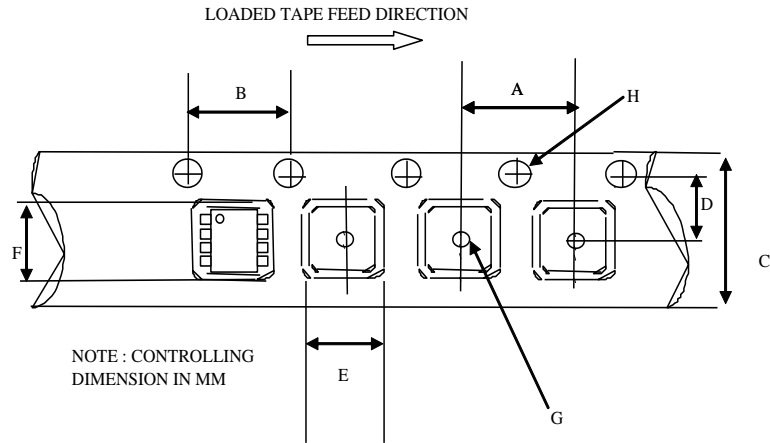


Figure 19B. Output Sink Current vs. Supply Voltage

Package Details: 8-Lead SOIC

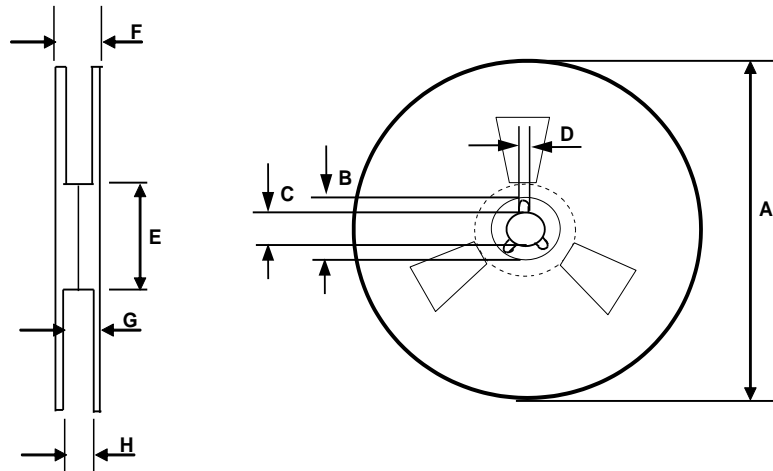


Tape and Reel Details: 8-Lead SOIC



CARRIER TAPE DIMENSION FOR 8SOICN

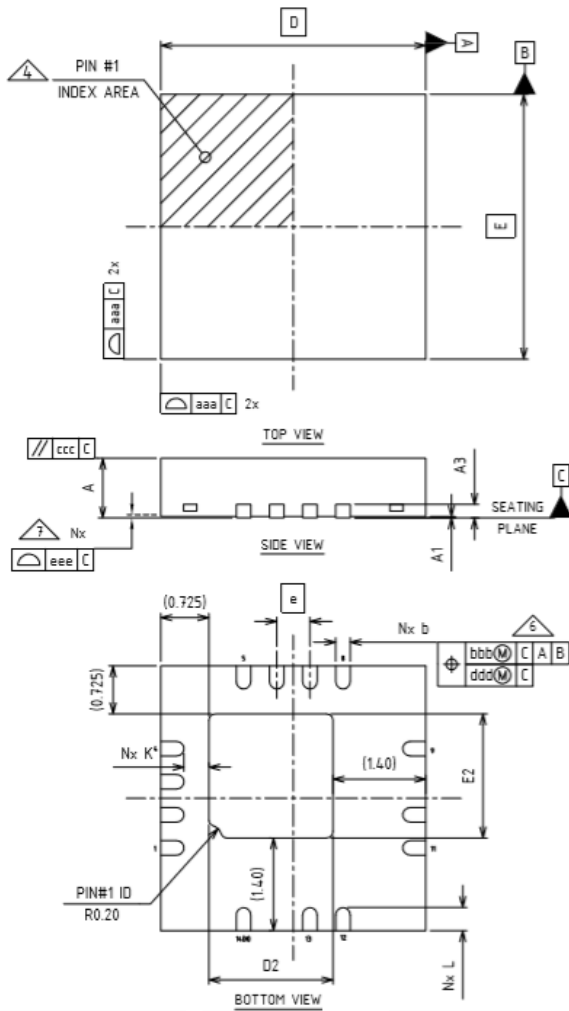
| Code | Metric | | Imperial | |
|------|--------|-------|----------|-------|
| | Min | Max | Min | Max |
| A | 7.90 | 8.10 | 0.311 | 0.318 |
| B | 3.90 | 4.10 | 0.153 | 0.161 |
| C | 11.70 | 12.30 | 0.46 | 0.484 |
| D | 5.45 | 5.55 | 0.214 | 0.218 |
| E | 6.30 | 6.50 | 0.248 | 0.255 |
| F | 5.10 | 5.30 | 0.200 | 0.208 |
| G | 1.50 | n/a | 0.059 | n/a |
| H | 1.50 | 1.60 | 0.059 | 0.062 |



REEL DIMENSIONS FOR 8SOICN

| Code | Metric | | Imperial | |
|------|--------|--------|----------|--------|
| | Min | Max | Min | Max |
| A | 329.60 | 330.25 | 12.976 | 13.001 |
| B | 20.95 | 21.45 | 0.824 | 0.844 |
| C | 12.80 | 13.20 | 0.503 | 0.519 |
| D | 1.95 | 2.45 | 0.767 | 0.096 |
| E | 98.00 | 102.00 | 3.858 | 4.015 |
| F | n/a | 18.40 | n/a | 0.724 |
| G | 14.50 | 17.10 | 0.570 | 0.673 |
| H | 12.40 | 14.40 | 0.488 | 0.566 |

Package Details: 14-Lead MLPQ 4x4

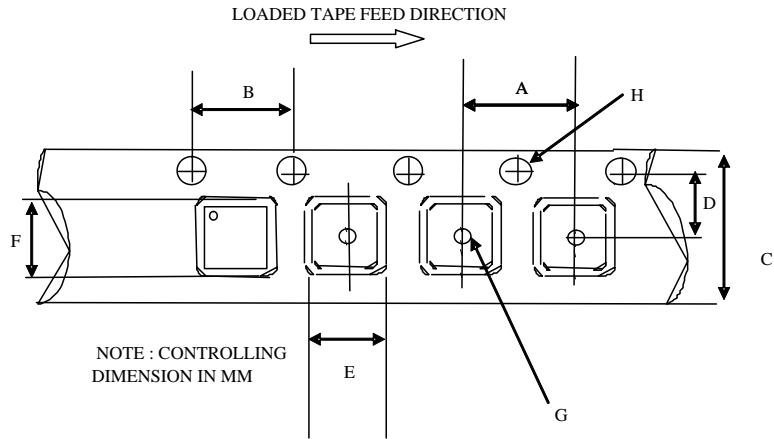


NOTE:

1. Dimensioning and tolerancing conform to ASME Y14.5-2009.
2. All dimensions are in millimeters.
3. N is the total number of terminals.
4. The location of the marked terminal #1 identifier is within the hatched area.
5. ND and NE refer to the number of terminals on each D and E side respectively.
6. Dimension b applies to the metalized terminal and is measured between 0.15mm and 0.30mm from the terminal tip. If the terminal has a radius on the other end of it, dimension b should not be measured in that radius area.
7. Coplanarity applies to the terminals and all other bottom surface metalization.

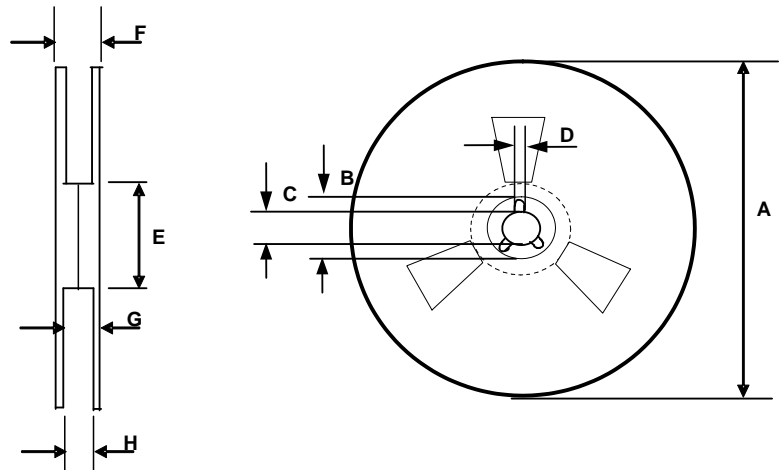
| Dimension Table | | | | |
|------------------|------------|----------|---------|------|
| Thickness Symbol | V | | | NOTE |
| | MINIMUM | NOMINAL | MAXIMUM | |
| A | 0.80 | 0.90 | 1.00 | |
| A1 | 0.00 | 0.02 | 0.05 | |
| A3 | --- | 0.20 Ref | --- | |
| b | 0.18 | 0.25 | 0.30 | 6 |
| D | 4.00 BSC | | | |
| E | 4.00 BSC | | | |
| e | 0.50 BSC | | | |
| D2 | 1.725 | 1.875 | 1.975 | |
| E2 | 1.725 | 1.875 | 1.975 | |
| K | 0.20 | --- | --- | |
| L | 0.25 | 0.35 | 0.45 | |
| aaa | 0.05 | | | |
| bbb | 0.10 | | | |
| ccc | 0.10 | | | |
| ddd | 0.05 | | | |
| eee | 0.08 | | | |
| N | 14 | | | 3 |
| ND | SEE FIGURE | | | 5 |
| NE | SEE FIGURE | | | |
| NOTES | 1, 2 | | | |

Tape and Reel Details: 14-Lead MLPQ 4x4



CARRIER TAPE DIMENSION FOR MLPQ4x4

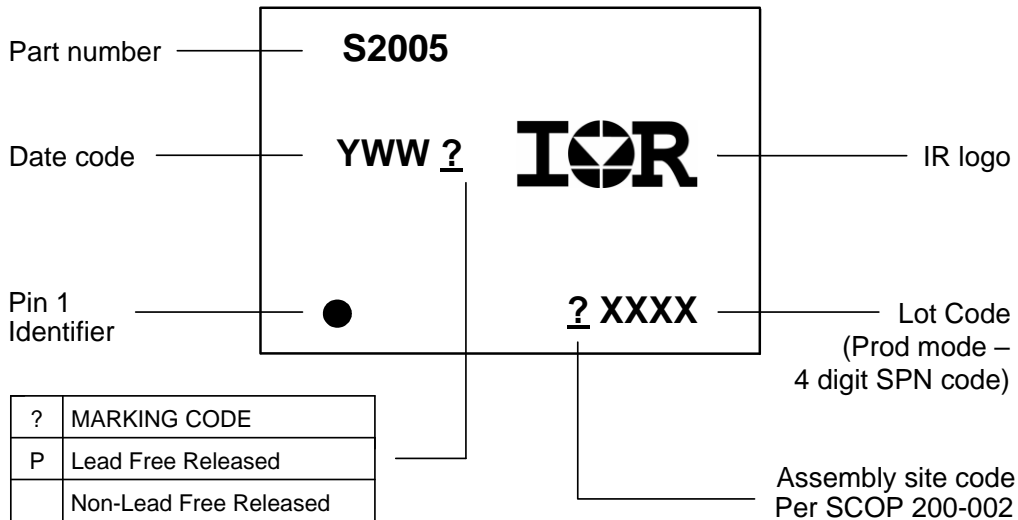
| Code | Metric | | Imperial | |
|------|--------|-------|----------|-------|
| | Min | Max | Min | Max |
| A | 7.90 | 8.10 | 0.311 | 0.358 |
| B | 3.90 | 4.10 | 0.153 | 0.161 |
| C | 11.70 | 12.30 | 0.461 | 0.484 |
| D | 5.45 | 5.55 | 0.215 | 0.219 |
| E | 4.25 | 4.45 | 0.168 | 0.176 |
| F | 4.25 | 4.45 | 0.168 | 0.176 |
| G | 1.50 | n/a | 0.069 | n/a |
| H | 1.50 | 1.60 | 0.069 | 0.063 |



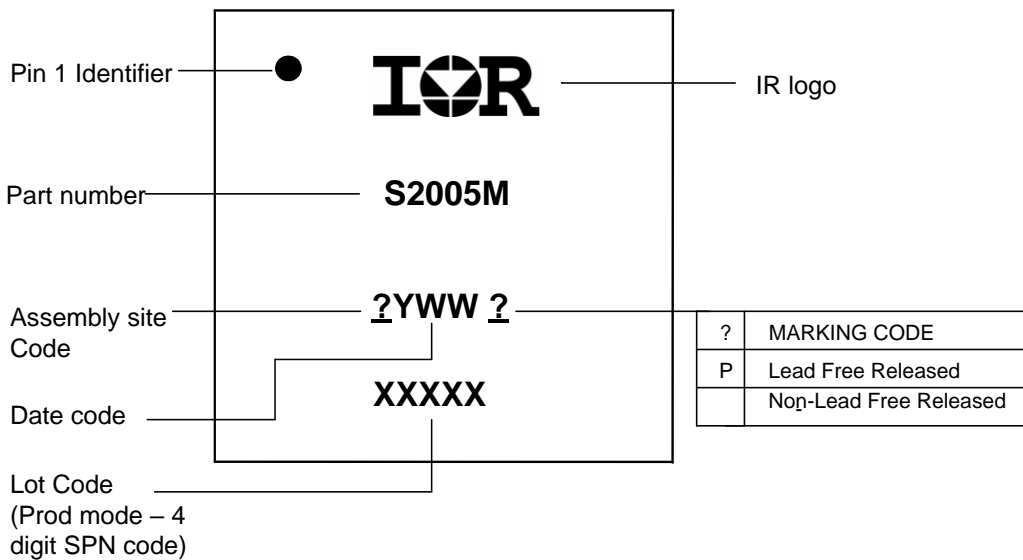
REEL DIMENSIONS FOR MLPQ4x4

| Code | Metric | | Imperial | |
|------|--------|--------|----------|--------|
| | Min | Max | Min | Max |
| A | 329.60 | 330.25 | 12.976 | 13.001 |
| B | 20.95 | 21.45 | 0.824 | 0.844 |
| C | 12.80 | 13.20 | 0.503 | 0.519 |
| D | 1.95 | 2.45 | 0.767 | 0.096 |
| E | 98.00 | 102.00 | 3.858 | 4.015 |
| F | n/a | 18.40 | n/a | 0.724 |
| G | 14.50 | 17.10 | 0.570 | 0.673 |
| H | 12.40 | 14.40 | 0.488 | 0.566 |

Part Marking Information



**8-Lead SOIC8
 IRS2005SPBF**



**14-Lead MLPQ 4x4
 IRS2005MPBF**

Qualification Information†

| | | | |
|-----------------------------------|------------------|---|---|
| Qualification Level | | Industrial†† | |
| | | Comments: This family of ICs has passed JEDEC's Industrial qualification. IR's Consumer qualification level is granted by extension of the higher Industrial level. | |
| Moisture Sensitivity Level | | 8 Lead SOIC | MSL2†††, 260°C (per IPC/JEDEC J-STD-020) |
| | | 14-Lead MLPQ 4x4 | |
| ESD | Human Body Model | Class 2 (per JEDEC standard JESD22-A114) | |
| | Machine Model | Class A (per EIA/JEDEC standard EIA/JESD22-A115) | |
| IC Latch-Up Test | | Class I (per JESD78) | |
| RoHS Compliant | | Yes | |

- † Qualification standards can be found at International Rectifier's web site <http://www.irf.com/>
- †† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.
- ††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.